# SUM70030M

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**Vishay Siliconix** 





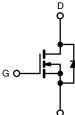
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	100			
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS}$ = 10 V	0.0035			
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS}$ = 7.5 V	0.0037			
Q <sub>g</sub> typ. (nC)	142.4			
I <sub>D</sub> (A) <sup>d</sup>	150			
Configuration	Single			

### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- Maximum 175 °C junction temperature
- Very low Q<sub>ad</sub> reduces power loss from passing through V<sub>plateau</sub>
- 100 %  $R_{\alpha}$  and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

- Power supply - Secondary synchronous rectification
- DC/DC converter
- · Power tools
- Motor drive switch
- DC/AC inverter
- · Battery management
- OR-ing / e-fuse



N-Channel MOSFET

ORDERING INFORMATION	
Package	D <sup>2</sup> PAK (TO-263-7L)
Lead (Pb)-free and halogen-free	SUM70030M-GE3

ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>C</sub> = 25 °C, unle	ss otherwise note	d)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V <sub>DS</sub>	100	N/	
Gate-source voltage		V <sub>GS</sub>	± 20	V	
Continuous drain current (T <sub>J</sub> = 150 °C)	T <sub>C</sub> = 25 °C		150 <sup>d</sup>		
	T <sub>C</sub> = 70 °C	I <sub>D</sub>	150 <sup>d</sup>	•	
Pulsed drain current (t = 100 µs)		I <sub>DM</sub>	500	A	
Avalanche current		I <sub>AS</sub>	60		
Single avalanche energy <sup>a</sup>	L = 0.1 mH	E <sub>AS</sub>	180	mJ	
	T <sub>C</sub> = 25 °C	D	375 <sup>b</sup>	w	
Maximum power dissipation <sup>a</sup>	T <sub>C</sub> = 125 °C	– P <sub>D</sub> –	125 <sup>b</sup>	1 **	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction-to-ambient (PCB mount) <sup>c</sup>	R <sub>thJA</sub>	40	°C/W	
Junction-to-case (drain)	R <sub>thJC</sub>	0.4	0/10	

#### Notes

a. Duty cycle  $\leq$  1 %

b. See SOA curve for voltage derating

c. When mounted on 1" square PCB (FR4 material)

d. Package limited

S20-0694-Rev. A, 14-Sep-2020

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RoHS

COMPLIANT

HALOGEN

FREE

SUM70030M

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	•						
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	100	-	-	- V	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	2	-	V		
Gate-body leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 250	nA	
		V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V	-	-	1		
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	150	μΑ	
		$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	5	mA	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \geq 10 \text{ V},  V_{GS} = 10 \text{ V}$	120	-	-	А	
Dursing a survey and state use interest &		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0029	0.0035	0	
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 7.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	-	0.0031	0.0037	Ω	
Forward transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	110	-	S	
Dynamic <sup>b</sup>	•						
Input capacitance	Ciss		-	10 870	-		
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V, V_{DS} = 50 V, f = 1 MHz$	-	820	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>		-	40	-		
Total gate charge <sup>c</sup>	Qg		-	142.4	214		
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	46.8	-	nC	
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>		-	18.5	-	no	
Output charge	Q <sub>oss</sub>	$V_{DS} = 50 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	138	207		
Gate resistance	R <sub>g</sub>	f = 1 MHz	0.34	1.7	3.4	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>		-	30	60		
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 50 \text{ V}, \text{ R}_{L} = 3 \Omega$	-	13	26		
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 10$ Å, $V_{GEN} = 10$ V, $R_g = 1$ $\Omega$	-	50	100	ns	
Fall time <sup>c</sup>	t <sub>f</sub>		-	15	30		
Drain-Source Body Diode Ratings a	and Characte	ristics <sup>b</sup> (T <sub>C</sub> = 25 °C)					
Pulsed current (t = 100 μs)	I <sub>SM</sub>		-	-	250	А	
Forward voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 10 A, V <sub>GS</sub> = 0 V	-	0.8	1.5	V	
Reverse recovery time	t <sub>rr</sub>		-	76	150	ns	
Peak reverse recovery charge	I <sub>RM(REC)</sub>		-	4.6	5.6	А	
Reverse recovery charge	Q <sub>rr</sub>	I <sub>F</sub> = 34 A, di/dt = 100 A/µs	-	0.205	0.24	μC	
Reverse recovery fall time	t <sub>a</sub>		-	52	-		
Reverse recovery rise time	t <sub>b</sub>		-	24	-	ns	

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

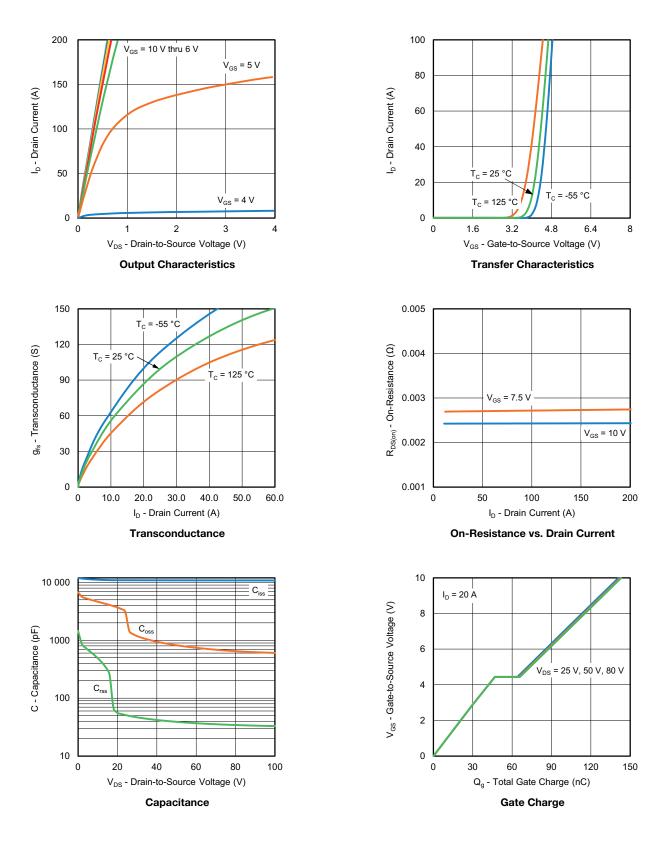
b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



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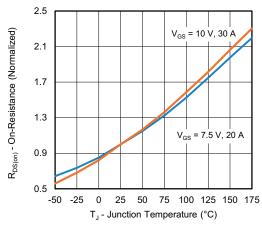
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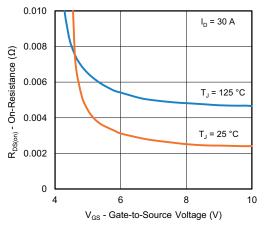
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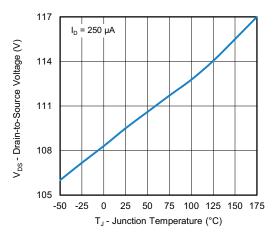
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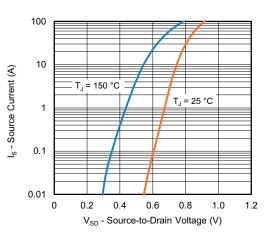
**On-Resistance vs. Junction Temperature** 



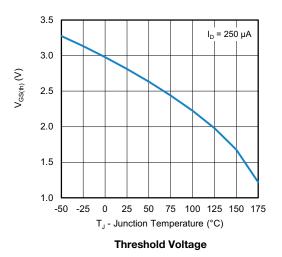
**On-Resistance vs. Gate-to-Source Voltage** 

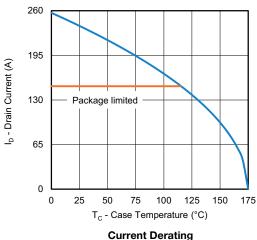


Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage





S20-0694-Rev. A, 14-Sep-2020

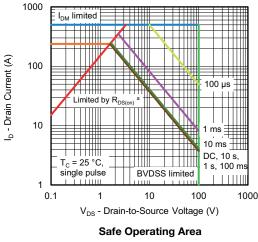
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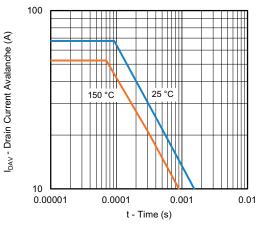
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### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

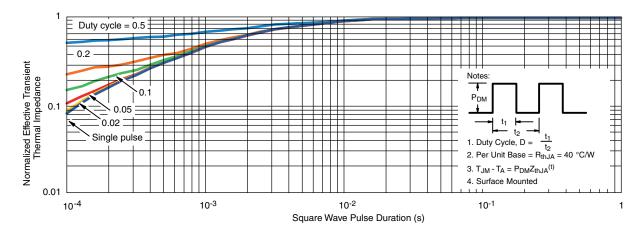




Single Pulse Avalanche Current Capability vs. Time

Note

a.  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$ 





### Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

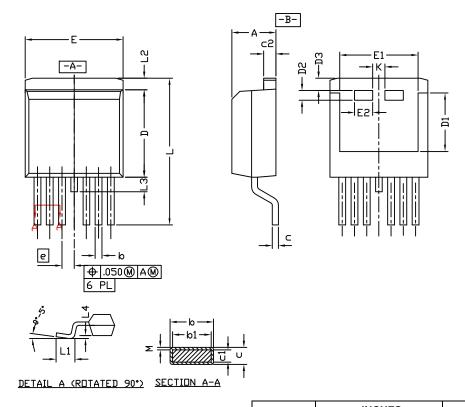
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?77104">www.vishay.com/ppg?77104</a>.

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## D<sup>2</sup>PAK (TO-263-7L) Case Outline



#### Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin to pin coplanarity max. 4 mils.
- 4. Lead thickness 25 mils.
- 5. For SUM part numbers lead thickness is 24 mils to 29 mils.
- 6. For reference only.
- 7. Use inches as the primary measurement.
- 8. This feature is only for SUM.

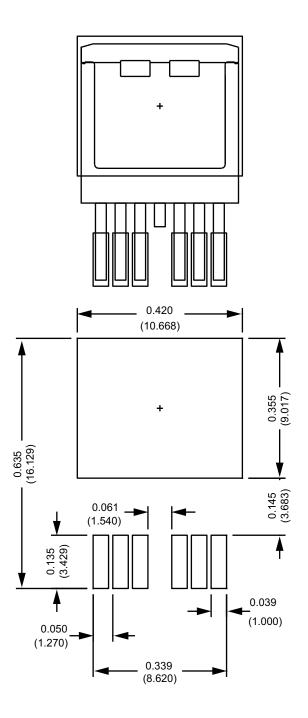
	INCHES		MILLIMETERS	
DIM.	MIN.	MAX.	MIN.	MAX.
А	0.160	0.190	4.064	4.826
b	0.020	0.039	0.508	0.990
b1	0.020	0.035	0.508	0.889
b2	0.045	0.055	1.143	1.397
c* SUB	0.012	0.018	0.305	0.457
c* SUM	0.022	0.028	0.559	0.711
c1	0.018	0.025	0.457	0.635
c2	0.045	0.055	1.143	1.397
D	0.340	0.380	8.636	9.652
D1	0.220	0.240	5.588	6.096
D2	0.038	0.042	0.965	1.067
D3	0.045	0.055	1.143	1.397
E	0.380	0.410	9.652	10.414
E1	0.245	-	6.223	-
E2	0.072	0.078	1.829	1.981
е	0.050	BSC	1.27 BSC	
K	0.045	0.055	1.143	1.397
L	0.575	0.625	14.605	15.875
L1	0.090	0.110	2.286	2.794
L2	0.040	0.055	1.016	1.397
L3	0.050	0.070	1.270	1.778
L4	0.010 BSC		0.254 BSC	
М	-	0.002	-	0.050
ECN: T13-0709-Rev. B, 30-Sep-13 DWG: 6006				

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# Recommended Land Pattern D<sup>2</sup>PAK (TO-263-7L)





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